

BSC205N10LS G

Request a Quote

BSC205N10LS G Information

		BSC205N10LS G Infineon Technologies Discrete Semiconductor Products	Į
wyournetsenet.com	Description Package	Transistors - FETs, MOSFETs - Single MOSFET N-CH 100V 45A TDSON-8 8-PowerTDFN	
For Reference Only		For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSC205N10LS G Specifications

Manufacturer Part Number	BSC205N10LS G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	7.4A (Ta), 45A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.4V @ 43µA
Gate Charge (Qg) (Max) @ Vgs	41nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2900pF @ 50V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	76W (Tc)
Rds On (Max) @ Id, Vgs	20.5 mOhm @ 45A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TDSON-8
Package / Case	8-PowerTDFN
	Report errors?

BSC205N10LS G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BSC205N10LS G Payment Methods



BSC205N10LS G Shipping Methods



If you have any question about BSC205N10LS G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com